

MAINTENANCE MANUAL

851-870 MHz, 90 WATT POWER AMPLIFIER ASSEMBLY 19D432307G3, G4

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DESCRIPTION

The power amplifier assembly uses four grounded base RF power transistors in Parallel to provide a minimum of 90 watts output power, R24 located on the Driver PA module, is used to adjust the output power to any level from 30 watts to rated RF power output.

SUPPLY VOLTAGE AND METERING

Supply voltage is connected through power leads from the system board to feed-through capacitor C217. C217 prevents RF from getting on the power leads.

Centralized metering jack J213 is provided for use with GE Test Model 4EX3All or Test Kit 4EX8Kl2. The test set meters the Power In (Driver Output), the Power Output, and the PA current.

CIRCUIT ANALYSIS

PA ASSEMBLY

The 35 Watt Driver Output is coupled through a 50 ohm RF cable to the PA input connector J211. The RF input is applied to the RF power splitter board. The RF power splitter consisting of micro strip transmission line W6 thru W12, W22 thru W26, W36, R1, R2 and R3, and has a 50 ohm input and output impedance. The outputs of the power splitter are applied to the four identical Class C Power Amplifiers Q201 through Q204 via their respective identical matching networks.

Part of the RF input is rectified by CR1 and metered at J213-4 through resistor R15. The rectified RF is a relative reading of RF Power Input.

— CAUTION —

The placement of monolithic capacitors on the PA board is very critical; therefore, it is not recommended that the PA board be serviced in the field.

Supply voltage for Q201 through Q204 is coupled through identical stabilizing networks and the collector feed networks. Supply voltage is measured in position K on the 15 volt range with the polarity switch in the (-) position (read as 15 volts full scale).

Collector current for Q201 through Q204 is metered across paralleled tapped manganin resistors R13 and R14 located on the PA module. The reading is taken in Position G in the Test 1 position on the 3 Volt scale with the "High" Sensitivity Button pressed, and read as 30 amperes full scale.

The outputs of Q201 through Q204 are coupled through identical matching networks to the RF power combiner board. The RF power combiner consists of micro strip transmission line W13 thru W19, W27 thru W32, W39 thru W42, R8 thru R10, and has a 50 ohm input and output impedance. The combiner adds the outputs of Q201 through Q204 and applies the combined RF output to the Low Pass Filter through the 50 ohm micro strip W19.

Z1 is a balance network adjusted at the factory for maximum power output. R8, R9 and R10 share equal amounts of power when Z1 is adjusted for maximum power output at a particular frequency.

Part of the RF output is rectified by CR2 and metered at J213-3 through resistor Rll. The rectified RF is a relative reading of RF Power Output.

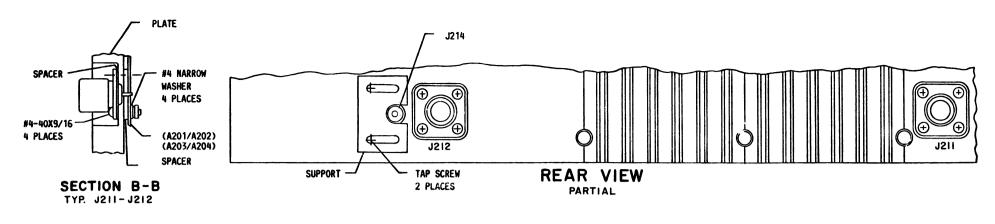
The output of the Low Pass Filter is coupled to the Antenna Switch K1 through the 50 ohm micro strip W33 or if the Antenna Switch is not used W35 couples the output to the Antenna J212.

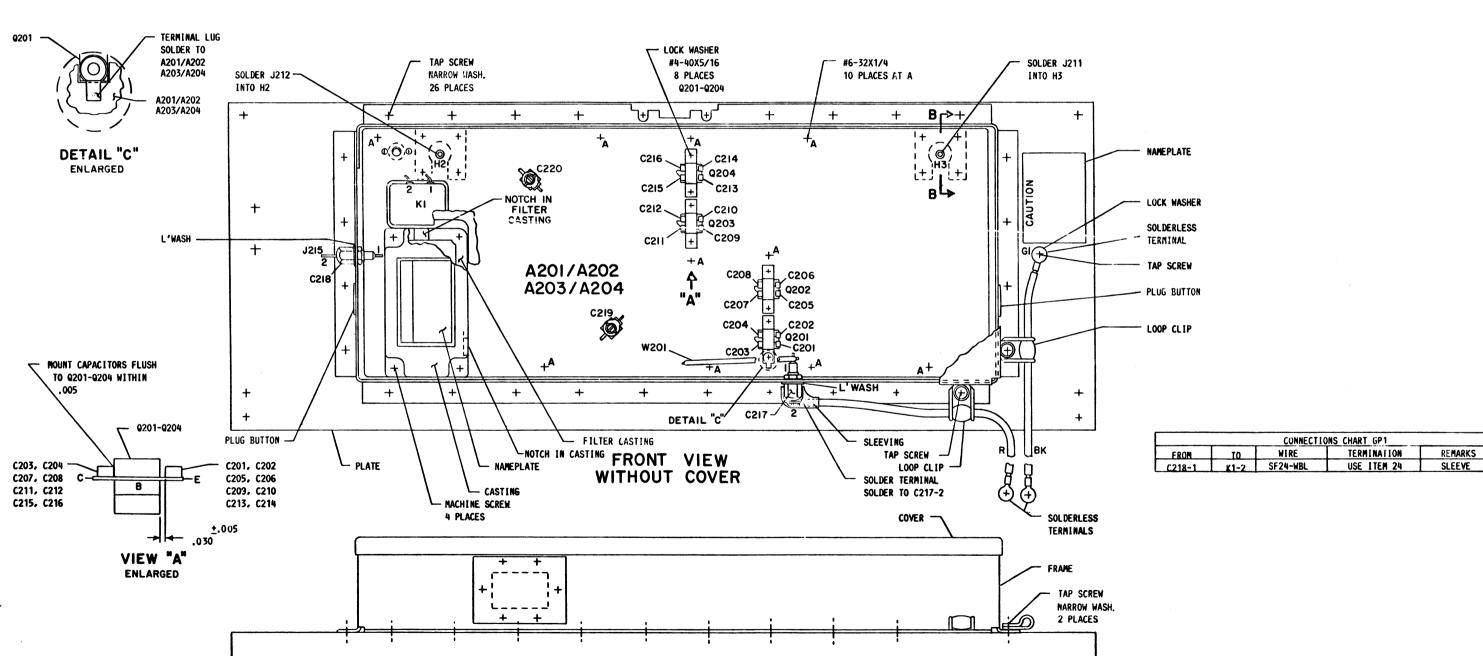
- WARNING -

The RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

GENERAL ELECTRIC COMPANY MOBILE COMMUNICATIONS DIVISION WORLD HEADQUARTERS LYNCHBURG, VIRGINIA 24502 U.S.A.







HEATSINK

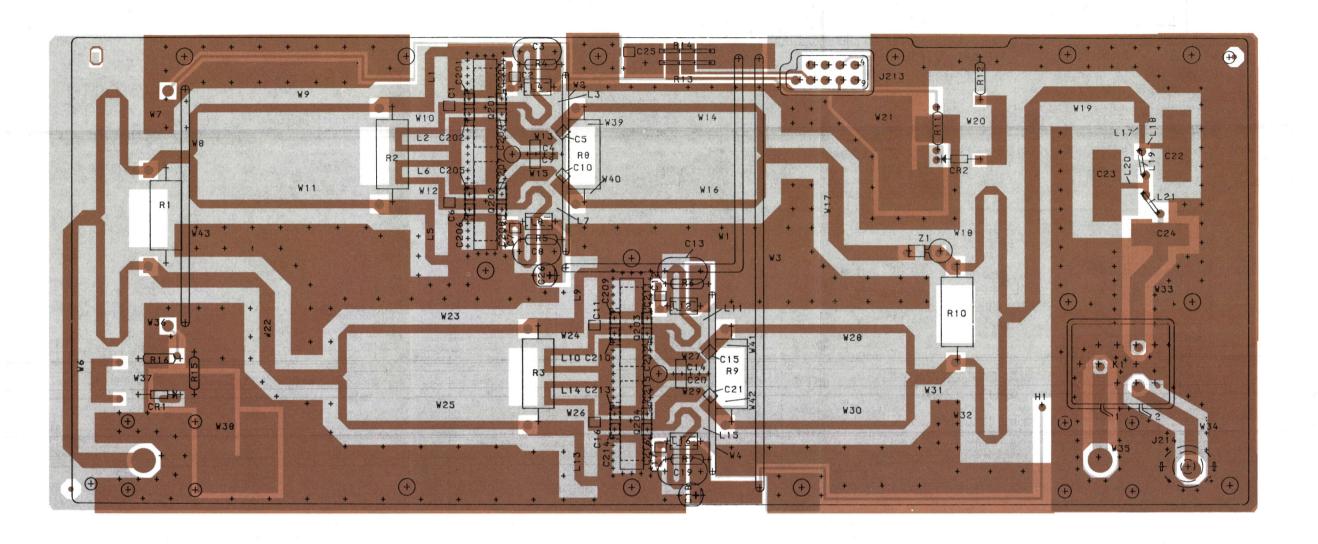
(19D432772, Rev. 2)

HEATSINK

OUTLINE DIAGRAM

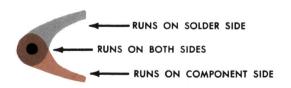
POWER AMPLIFIER 19D432307G3, G4

TAP SCREW



-	CC	INNECTIONS	CHART GP3	
FROM	TO	WIRE	TERMINATION	REMARKS
H1	K1-1	SF24-R	USE ITEM 8	SLEEVE

(19D433084, Rev. 1) (19A144059, Sh. 1, Rev. 1) (19A144059, Sh. 2, Rev. 1)

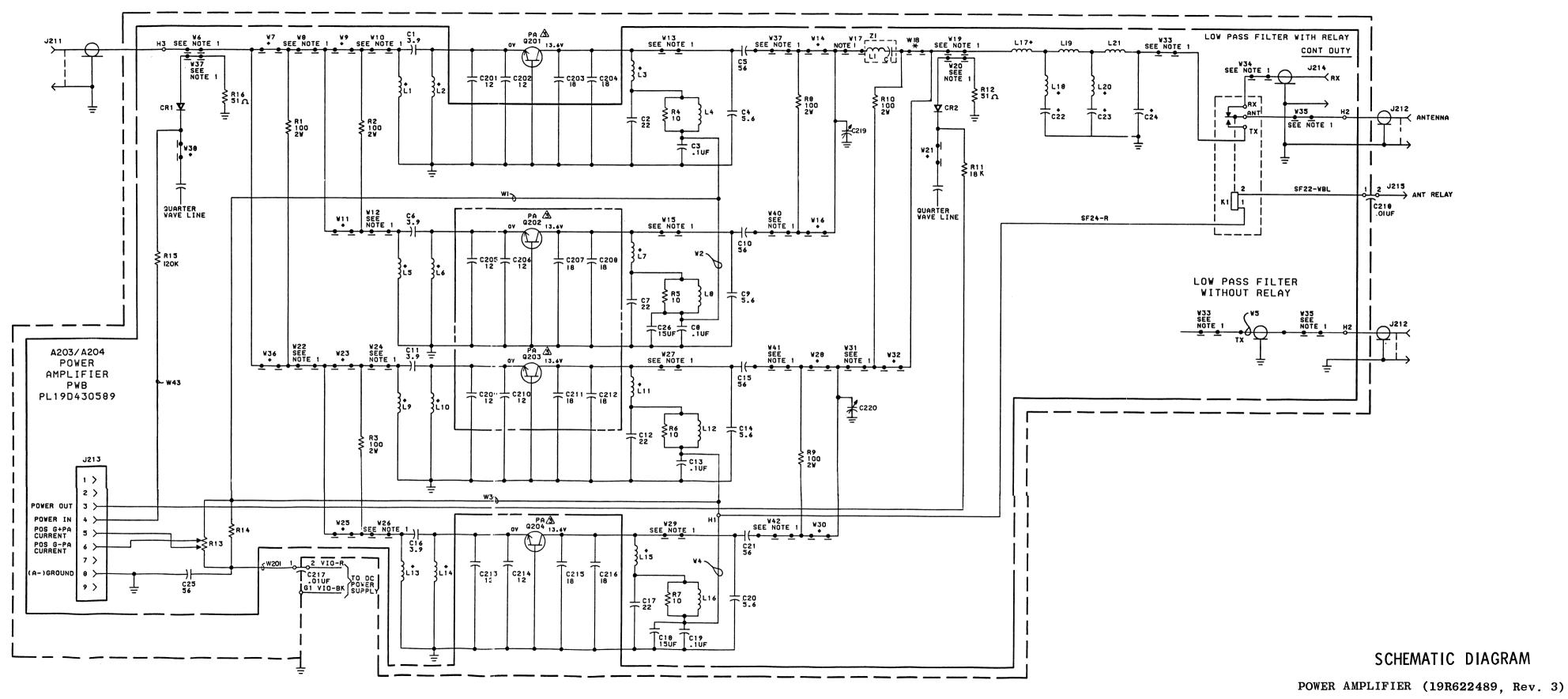


OUTLINE DIAGRAM

PA BOARD

4

Issue 3



Issue 3

LBI31033

PARTS LIST

851 MHz, 90 WATT
POWER AMPLIFIER
19D432307G3 WITH RELAY - REV. A
19D432307G4 WITHOUT RELAY - REV. A
ISSUE 3

SYMBOL	GE PART NO.	DESCRIPTION
A203		90 WATT POWER AMPLIFIER
and A204		A203 19D430589G3 WITH RELAY A204 19D430589G4 WITHOUT RELAY
		REV A
C1	19A134418P3	Ceramic: 3.9 pF ±0.25 pF, 50 VDCW.
C2	19A134481P21	Ceramic: 22 pF ±5%, 50 VDCW.
C3	19A116080P107	Polyester: 0.1 uF ±10%, 50 VDCW.
C4	19A703967P1	Porcelain: 5.6 pF \pm .25 pF, 500 VDCW; sim to ATC 100 85R6 CNS 500X.
C5	19A134418P31	Ceramic: 56 pF \pm 5%, 50 VDCW, temp coef 0 \pm 30 pPM.
C6	19A134418P3	Ceramic: 3.9 pF ±0.25 pF, 50 VDCw.
C7	19A134418P21	Ceramic: 22 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM
C8	19A116080P107	Polyester: 0.1 uF ±10%, 50 VDCW.
С9	19A703967P1	Porcelain: 5.6 pF ±.25 pF, 500 VDCW; sim to ATC 100 85R6 CNS 500X.
C10	19A134418P31	Ceramic: 56 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM
C11	19A134418P3	Ceramic: 3.9 pF ±0.25 pF, 50 VDCW.
C12	19A134418P21	Ceramic: 22 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM
C13	19A116080P107	Polyester: 0.1 uF ±10%, 50 VDCW.
C14	19A703967P1	Porcelain: 5.6 pF ±.25 pF, 500 VDCW; sim to ATC 100 85R6 CNS 500X.
C15	19A134418P31	Ceramic: 56 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM
C16	19A134418P3	Ceramic: 3.9 pF ±0.25 pF, 50 VDCW.
C17	19A134418P21	Ceramic: 22 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM
C18	19A134202P8	Tantalum: 15 uF ±20%, 20 VDCW.
C19	19A116080P107	Polyester: 0.1 uF ±10%, 50 VDCW.
C20	19A703967P1	Porcelain: 5.6 pF ±.25 pF, 500 VDCW; sim to ATC 100 85R6 CNS 500X.
C21	19A134418P31	Ceramic: 56 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM
C22 thru C24		(Part of printed board 19D433083P1).
C25	19A134418P31	Ceramic: 56 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM
C26	19A134202P8	Tantalum: 15 uF ±20%, 20 VDCW.
		DIODES AND RECTIFIERS
CR1	19A116052P2	Silicon, fast recovery; sim to Hewlett Packard
and CR2	10	5082-2811.
		JACKS AND RECEPTACLES
J213	19B219374G1	Connector: 9 contacts.
J214	19A700049P2	Connector, receptacle; 500 VDCW maximum; sim to NTTF-1058.
K1	19A116722P1	Hermetic sealed: 125 ohms ±20%, 1 form C contact, 9.6 to 15.8 VDC (over the temperature range indicated).
7.1		
L1 thru L3		(Part of printed board 19D433083P1).
L4	19A129773G1	Coil.
L5 thru		(Part of printed board 19D433083P1).

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
L8	19A701091G1	Coil.	C213	19A134418P15	Ceramic: 12 pF +5%, 50 VDCW.
L9 thru L11		(Part of printed board 19D433083P1).	and C214	10010110110	Columbia. Al pr. 1000, oc 15000
L12	19A701091G1	Coil.	C215 and C216	19A134418P19	Ceramic: 18 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM.
L13 thru L15		(Part of printed board 19D433083P1).	C217	19A116708P1	Ceramic: 0.01 uF -0 +100%, 500 VDCW, rated 20 amps; sim to Erie 327050X5W0103P.
L16	19A701091G1	Coil.	C218	19A116708P1	Ceramic: 0.01 uF -0 +100%, 500 VDCW, rated 20 amps; sim to Erie 327050X5W0103P. (Includes
L17 and L18		(Part of printed board 19D433083P1).	C219 and	19A703518P2	J215). Variable: 1.44 to 5.20 pF, 125 VDCW; sim to EF Johnson 186-0607-175.
L19	19A136863P1	Coil.	C220		
L20	10110000001	(Part of printed board 19D433083P1).	J211	7777145P5	Receptacle: sim to Amphenol 82-97.
L21	19A136863P1	Coil.	and J212	7777145P5	neceptacie. Sim to Amphenoi 02-51.
			J215		(Part of C218).
R1 thru R3	19A700111P39	Composition: 100 ohms ±5%, 2 w.			
R4 thru	19A700106P15	Composition: 10 ohms ±5%, 1/4 w.	₩201	19A143402P4	Jumper.
R7 R8 thru	19A700111P39	Composition: 100 ohms ±5%, 2 w.			TRANSISTOR KIT 19A144208G1
R10					
R11	19A700019P52	Deposited carbon: 18K ohms ±5%, 1/4 w.	Q201 thru	19A143471P1	Silicon, NPN.
R12	19A700106P32 19C850605P1	Composition: 51 ohms ±5%, 1/4 w. Shunt resistor.	Q204		
and R14	1000000011	3,440 10010001			MISCELLANEOUS
R15	19A700019P62	Deposited carbon: 0.12M ohms ±5%, 1/4 w.		4029840P6	Contact, electrical: No. 22-24 AWG wire; sim to Malco 12080-0. (Located at K1-1 & K1-2).
R16	19A700106P32	Composition: 51 ohms ±5%, 1/4 w.		19C330572G1	Heat sink plate.
				19D417526G4	Frame.
W1	19A143402P3	Jumper.		19D417513G1	PA Cover.
W2	19A143402P1	Jumper.		19B233315G3	Filter Web.
W3	19A143402P2	Jumper.		19B226212G1	Heat sink. (Quantity 2).
W4	19A143402P1	Jumper.		19B226212G4 19D416275P3	Heat sink. (Quantity 3). Filter casting.
W5 W6	19A130607G3	Cable, RF: approx .7 of an inch. (Part of printed board 19D433083P1).		N80P13016C6	Machine screw, phillips head: No. 6-32 x 1.
thru W42		(tall of prince source represent).		19B209103P410	Tap screw, hex head: No. 8-32 x 5/8. (Secures heat sinks).
W43	19A143402P5	Jumper.		N80P9005C6	Machine screw, phillips head: No. 4-40 x 5/16. (Secures Q201-Q204).
7.1	10414405701			N405P5C6	Lockwasher, spring type: No. 4. (Secures Q201-Q204).
Z1 C1	19A144057G1 19A134227P 2	Network assembly. Includes: Variable, air: 2 - 7 pF, 100 VDCW, temp coef 0		7139898P3	Nut, hex, brass: No. 1/4-28. (Secures C217 &
L1	19A144056P1	±50 PPM.		19B201074P304	C218). Tap screw, Phillips POZIDRIV®: No. 6-32 x 1/4.
21	1341440071			19A701863P13	(Secures frame to plate). Cable clip. (Secures Red & Black power leads).
C201	19A134418P15	Ceramic: 12 pF ±5%, 50 VDCW.		19B201074P306	Tap screw, Phillips POZIDRIV⊕: No. 6-32 x 3/8.
and C202				19B209268P113	(Secures clip loops). Terminal, solderless: sim to AMP 2-34835-4.
C203 and C204	19A134418P19	Ceramic: 18 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM.		19B209260P11	(Located at C217). Solderless terminal. (Located on Red & Black power leads).
C205 and C206	19A134418P15	Ceramic: 12 pF ±5%, 50 VDCW.		N529P18E	Button plug. (Located on ends of frame).
C207 and	19A134418P19	Ceramic: 18 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM.		19B227679P2	Spacer. (Used with J211 & J212 on J211 & J212 side of plate).
C208 C209 and	19A134418P15	Ceramic: 12 pF ±5%, 50 VDCW.		19B227679P3 19B201074P305	Spacer. (Used with J211 & J212 on A201 & A202 side of plate). Tap screw, Phillips POZIDRIV®: No. 6-32 x 5/16.
C210					(Secures J214 support).
C211 and C212	19A134418P19	Ceramic: 18 pF ±5%, 50 VDCW, temp coef 0 ±30 PPM.		19A143455P1 19A142996G1	Support. (J214). Terminal lug. (Soldered to A201 & A202 at Q201)
C218				N403P13C6	Lockwasher: No. 6. (Located at G1 - Black lead
				NP280071	Nameplate, paper. (CAUTION).
				NP280901	Nameplate. (Tx Power Amplifier Metering).
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*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter," which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - Power Amplifier 19D432307

To permit tuning and balance of the power amplifier, added C219 and C220.

- REV. B To limit board flexure during temperature cycling, added two screws to conduct heat from the board to the heat sink.
- REV. A PA Board Assembly 19D430589

Changed location and value of capacitors C4, C9, C14 and C20. These capacitors were 19A134418P7: Ceramic; 5.6 pF ±5%, 50 VDCW.